Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Metal

**Overall Length:** 

1.253 inches

# **Mounting Facility Quantity:**

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-203aa

# Electrode Internally-electrically Connected To Case:

Cathode

### **Mounting Method:**

Threaded stud

**Overall Width Across Flats:** 

0.430 inches

Thread Size:

#### 0.250 inches

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

40.0 repetitive peak reverse voltage and 40.0 working peak reverse voltage and 48.0 nonrepetitive peak reverse voltage

## **Current Rating Per Characteristic:**

25.00 amperes forward current, average and 400.00 amperes forward current, average preset

# Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

## **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

1 tab, solder lug and 1 threaded stud

### **Specification Data:**

80131-release6612 professional/industrial association specification

### Shelf Life:

N/a

# Unit Of Measure:

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### Demilitarization:

No

# Fiig:

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